

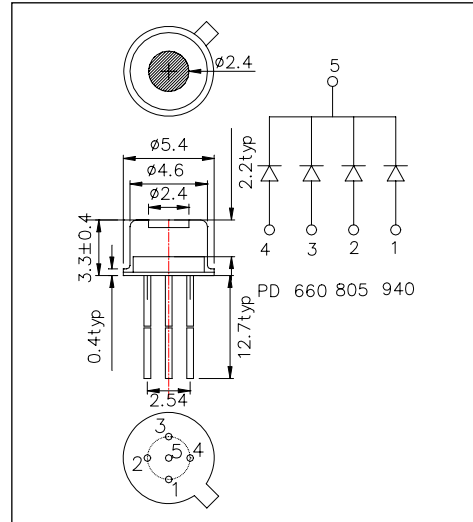
## L660/805/940/PD010-35B52 Multi-Wavelength LED

L660/805/940/PD010-35B52 consists of an AlGaAs(660, 805nm) and GaAs(940nm) LEDs, a Si-PD mounted on TO-18 stem hermetical sealed with a flat glass lens. It is designed to monitor reflected light through detector for controlling its own output power.

<Specifications>

1. Product Name: Multi-Wavelength LED Lamp
2. Type Number: L660/805/940/PD010-35B52
3. Chip:
  - Chip material: AlGaAs, GaAs, Si-PIN-PD
  - Peak Wavelength: 660,805,940nm
4. Package
  - Stem: TO-18 5pin type
  - Lens:  $\Phi 2.4$  Flat Glass

Outer Dimension (Unit:mm)



Absolute Maximum Ratings[Ta=25°C]						
Item	Symbol	Maximum Rated Value				Unit
		660nm	805nm	940nm	PD	
Power Dissipation	PD	120	170	140	-	mW
Forward Current	IF	50	100	100	-	mA
Pulse Forward Current	IFP	200	500	1000	-	mA
Reverse Voltage	VR	5			100	V
Operating Temperature	TOPR	-30 ~ +85				°C
Storage Temperature	TSTG	-30 ~ +100				°C
Soldering Temperature*	TSOL	260				°C

\* Soldering condition must be completed within 3 seconds at 260°C and is allowed in the area apart 3mm from the bottom of the lamp

Electro-Optical Characteristics [Ta=25°C ]													
Item	Symbol	Condition	Minimum			Typical			Maximum				Unit
			660	805	940	660	805	940	660	805	940	PD	
Forward Voltage	VF	IF=20mA				1.9	1.5	1.2	2.2	1.7	1.3		V
Reverse Current	IR	VR=5V							10				uA
T.Radiated Power*	PO	IF=20mA				2.9	3.5	2.5					mW
Peak wavelength	$\lambda P$	IF=20mA	650	795	935	660	805	940	670	915	955		nm
Half Width	$\Delta\lambda$	IF=20mA				20	30	45					nm
Output Current	IL	VR=10V				50	130	140					uA
Dark Current	ID	VR=10V										10	nA

\* Measured by Photodyne #500

